

N-Channel 250-V (D-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (A)		
250	0.155 at V _{GS} = 10 V	3.8		
	0.162 at V _{GS} = 6 V	3.7		

FEATURES

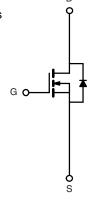
- Halogen-free According to IEC 61249-2-21 Available
- PWM-OptimizedTrenchFET[®] Power MOSFET
- 100 % R_q Tested
- Avalanche Tested





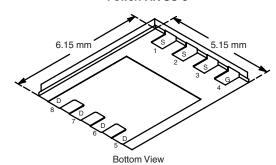
APPLICATIONS

- Primary Side Switch In:
 - Telecom Power Supplies
 - Distributed Power Architectures
 - Miniature Power Modules



N-Channel MOSFET

PowerPAK SO-8



Ordering Information: Si7434DP-T1-E3 (Lead (Pb)-free)

Si7434DP-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS \top	$_{A}$ = 25 °C, unles	ss otherwise r	oted		
Parameter	Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		V_{DS}	250		V
Gate-Source Voltage		V_{GS}	± 20		V
Continuous Drain Current (T _{.I} = 150°C) ^a	T _A = 25 °C	I _D	3.8	2.3	
Continuous Drain Current (1 j = 150 C)	T _A = 70 °C		3.0	1.8	
Pulsed Drain Current		I _{DM}	40		Α
Continuous Source Current (Diode Conduction) ^a		I _S	4.3	1.6	
Avalanche Current	L = 1.0 mH	I _{AS}	13		
Single Pulse Avalanche Energy	Pulse Avalanche Energy		8.4		mJ
Maximum Power Dissipation ^a	T _A = 25 °C	- P _D	5.2	1.9	W
Maximum Power Dissipation	T _A = 70 °C		3.3	1.2	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C
Soldering Recommendations (Peak Temperature) ^{b,c}			260		

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Marrian de Ameliant	t ≤ 10 s	- R _{thJA}	19	24	°C/W	
Maximum Junction-to-Ambient ^a	Steady State		52	65		
Maximum Junction-to-Case (Drain)	Steady State	R_{thJC}	1.5	1.8		

Notes:

- a. Surface Mounted on 1" x 1" FR4 board.
- b. See Solder Profile (www.vishay.com/ppg?73257). The PowerPAK 1212-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

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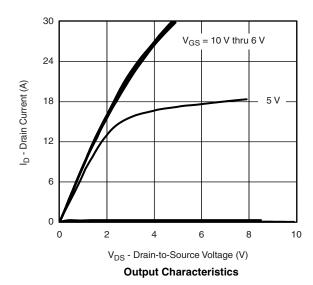


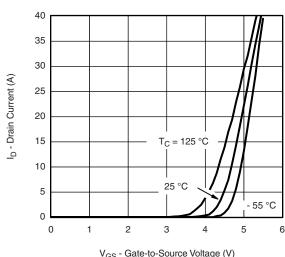
SPECIFICATIONS T _J = 25 °C, unless otherwise noted								
Parameter	Symbol	Test Condition	Min.	Тур.	Max.	Unit		
Static								
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	2.0		4.0	٧		
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA		
Zava Cata Valtaga Drain Current	1	V _{DS} = 250 V, V _{GS} = 0 V			1			
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 250 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 ^{\circ}\text{C}$			15	μΑ		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	30			Α		
5	В	V _{GS} = 10 V, I _D = 3.8 A		0.129	0.155	Ω		
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 6.0 \text{ V}, I_D = 3.7 \text{ A}$		0.131	0.162			
Forward Transconductance ^a	9 _{fs}	$V_{DS} = 15 \text{ V}, I_D = 3.8 \text{ A}$		14		S		
Diode Forward Voltage ^a	V_{SD}	I _S = 2.8 A, V _{GS} = 0 V		0.75	1.2	٧		
Dynamic ^b								
Total Gate Charge	Qg			34	50	nC		
Gate-Source Charge	Q_{gs}	$V_{DS} = 100 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 3.8 \text{ A}$		6.8				
Gate-Drain Charge	Q_{gd}			10.5				
Gate Resistance	R_g		0.6	1.2	1.8	Ω		
Turn-On Delay Time	t _{d(on)}			16	25			
Rise Time	$\begin{array}{c} t_r \\ \\ t_{d(off)} \end{array} \hspace{0.2in} V_{DD} = 100 \text{ V, } R_L = 25 \Omega \\ \\ I_D \cong 4.0 \text{ A, } V_{GEN} = 10 \text{ V, } R_g = 6 \Omega \end{array}$	V_{DD} = 100 V, R_L = 25 Ω		23	35			
Turn-Off Delay Time			47	70	ns			
Fall Time	t _f			19	30			
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 2.8 A, dl/dt = 100 A/μs		100	150			

Notes

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





V_{GS} - Gate-to-Source Voltage (V) **Transfer Characteristics**

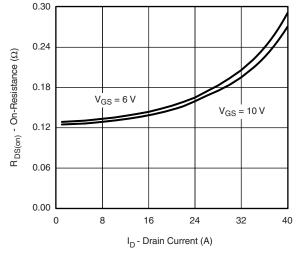
a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %. b. Guaranteed by design, not subject to production testing.



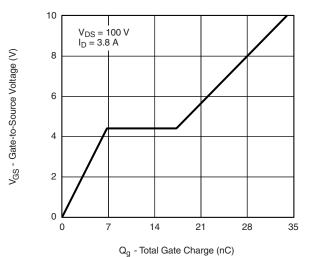




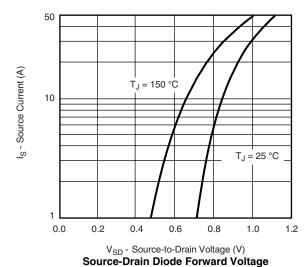
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

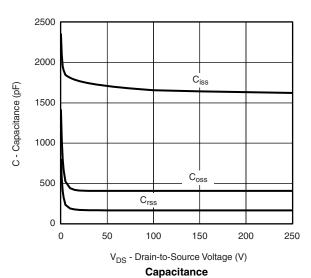


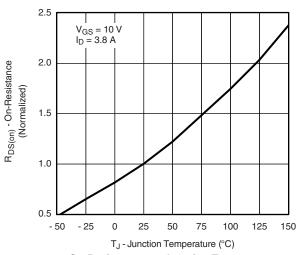
On-Resistance vs. Drain Current



Gate Charge







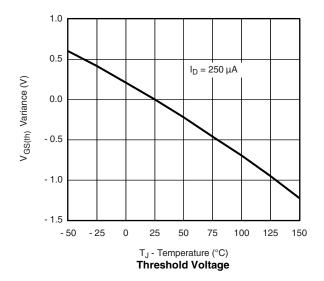
On-Resistance vs. Junction Temperature

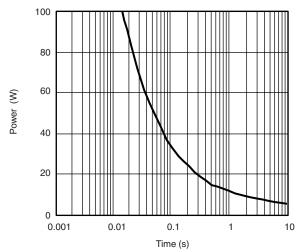


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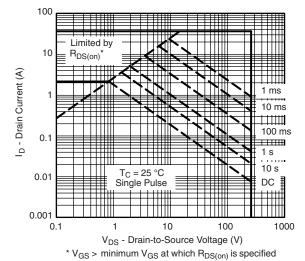
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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

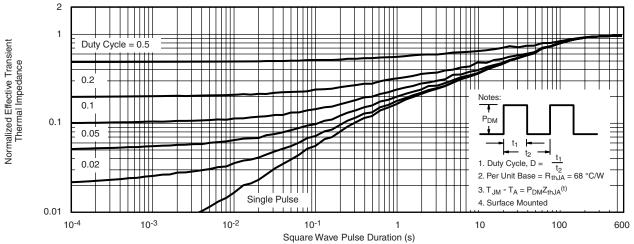




Single Pulse Power, Junction-to-Ambient



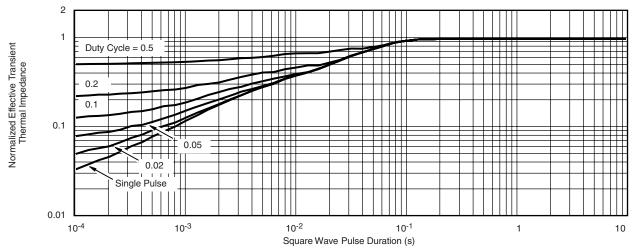
Safe Operating Area, Junction-to-Case



Normalized Thermal Transient Impedance, Junction-to-Ambient



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Case

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